NSN 5962-01-370-0996

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Maximum Power Dissipation Rating:
8880.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Schottky and bipolar
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Bipolar metal-oxide semiconductor
Case Outline Source And Designator:
D-8 mil-m-38510
Current Rating Per Characteristic:
-30.00 milliamperes collector cutoff current, dc, base open absolute and 5.00 milliamperes average forward current averaged over a full
60-hz cycle absolute
Terminal Surface Treatment:
Solder
Product Name:
Microcircuit, digital, schottky, bipolar 4096 prom
Voltage Rating And Type Per Characteristic:
-0.5 volts total supply and 7.0 volts total supply
Time Rating Per Chacteristic:
45.00 nanoseconds access
Memory Device Type:
Prom
Hybrid Technology Type:
Monolithic
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
20 printed circuit
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:
Yes - demil/mli
Fiig:

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